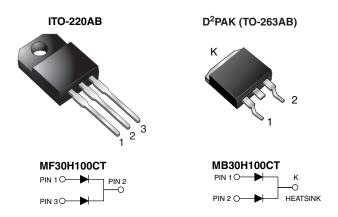


MB30H100CT, MF30H100CT

Vishay General Semiconductor

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 15 A				
V _{RRM}	100 V				
I _{FSM}	275 A				
V _F	0.67 V				
I _R	5.0 µA				
T _J max.	175 °C				
Package	ITO-220AB, D ² PAK (TO-263AB)				
Circuit configuration	Common cathode				

FEATURES

Power pack

- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- · High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)
- AEC-Q101 gualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: ITO-220AB, D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,....)

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 and HM3 suffix meets JESD 201 class 2 whisker test Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_C = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	MB30H100CT MF30H100CT		UNIT	
Device marking code		MBRB30H100CT	MBRF30H100CT		
Maximum repetitive peak reverse voltage	V _{RRM}	100			
Working peak reverse voltage	V _{RWM}	100		V	
Maximum DC blocking voltage	V _{DC}	100			
Maximum average forward rectified current total de		30			
(fig.1) per dio	de I _{F(AV)}	1	5		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		275		A	
Peak repetitive reverse surge current per diode at t_p = 2.0 µs, 1 k	kHz I _{RRM}	I _{RRM} 1.0			
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs	
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +175		°C	
Isolation voltage (ITO-220AB only) from terminal to heat sink t =	1 min V _{AC}	15	00	V	

RoHS COMPLIANT HALOGEN

FREE

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ELECTRICAL CHARACTERISTICS ($T_c = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT
Maximum instantaneous forward voltage per diode	V _F (1)	l _F = 15 A	T _J = 25 °C	0.82	- V
		l _F = 15 A	T _J = 125 °C	0.67	
		I _F = 30 A	T _J = 25 °C	0.93	
		I _F = 30 A	T _J = 125 °C	0.80	
Maximum reverse current per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	5.0	μA
			T _J = 125 °C	6.0	mA

Note

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width, \leq 40 ms

THERMAL CHARACTERISTICS ($T_c = 25$ °C unless otherwise noted)					
PARAMETER	SYMBOL	MB30H100CT	MF30H100CT	UNIT	
Typical thermal resistance per diode	$R_{ extsf{ heta}JC}$	1.9	4.6	°C/W	

ORDERING INFORMATION						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ITO-220AB	MF30H100CTHE3_B/P	1.99	Р	50/tube	Tube	
D ² PAK (TO-263AB)	MB30H100CTHM3/I	1.35	I	800/reel	Tape and reel	



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RATINGS AND CHARACTERISTICS CURVES ($T_C = 25$ °C unless otherwise noted)

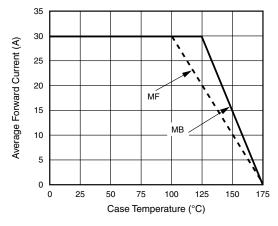


Fig. 1 - Forward Derating Curve Per Diode

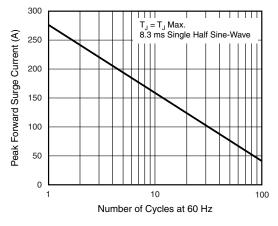
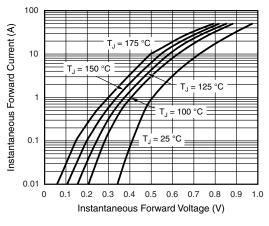
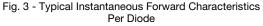


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode





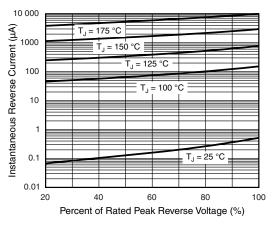


Fig. 4 - Typical Reverse Characteristics Per Diode

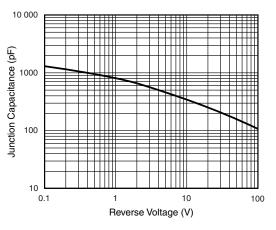


Fig. 5 - Typical Junction Capacitance Per Diode

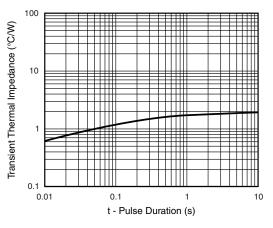


Fig. 6 - Typical Transient Thermal Impedance Per Diode

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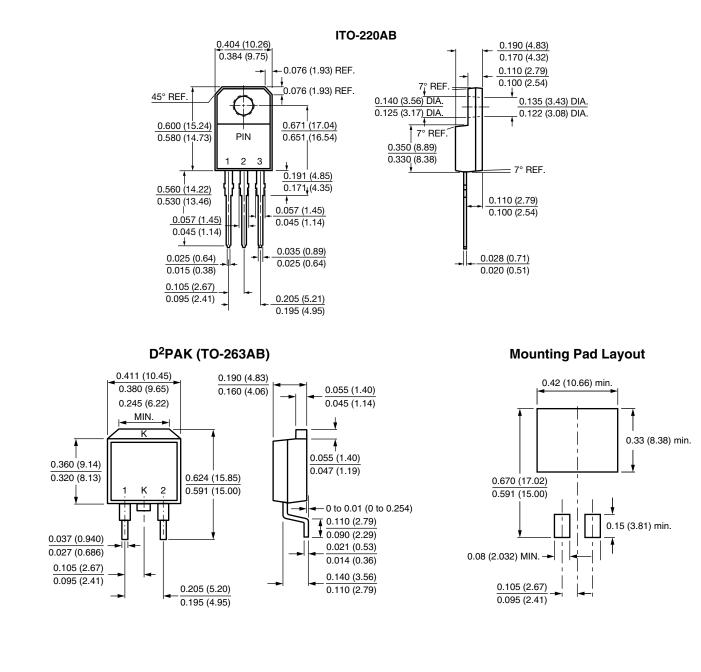
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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